TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

2SK3309

Switching Regulator Applications

- Low drain-source ON resistance: RDS (ON) = 0.48Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.3 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 100 \,\mu\text{A} \,(\text{max}) \,(V_{DS} = 450 \,\text{V})$
- Enhancement-mode: $V_{th} = 3.0 \sim 5.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	450	(V)
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V_{DGR}	450	(/x/ s)
Gate-source voltage			V_{GSS}	±30	V
Drain current	DC	(Note 1)	I _D	10	A
	Pulse	(Note 1)	I _{DP}	40	> ^
Drain power dissipation (Tc = 25°C)			P_{D}	65	W
Single pulse avalanche energy (Note 2)			EAS	222	mJ
Avalanche current			I _{AR}	10	<< <u>A</u>
Repetitive avalanche energy (Note 3)			EAR	6.5	mУ
Channel temperature			Teh	150	°C
Storage temperature range			(T _{stg}	−55 ~ 150	∕/°c

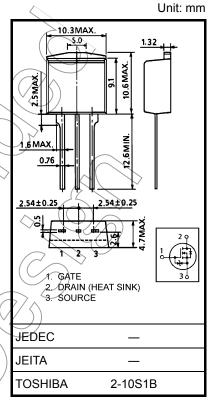
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

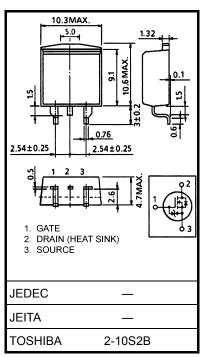
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	1.92	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

- Note 1: Please use devise on condition that the channel temperature is below 150°C.
- Note 2: VDD = 90 V, Tch = 25°C (initial), L = 3.7 mH, RG = 25 $\Omega,$ IAR = 10 A
- Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.



Weight: 1.5 g (typ.)



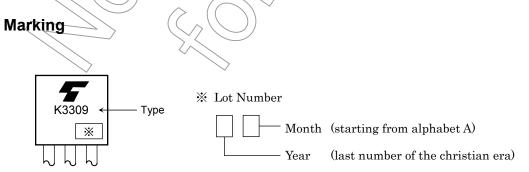
Weight: 1.5 g (typ.)

Electrical Characteristics (Ta = 25°C)

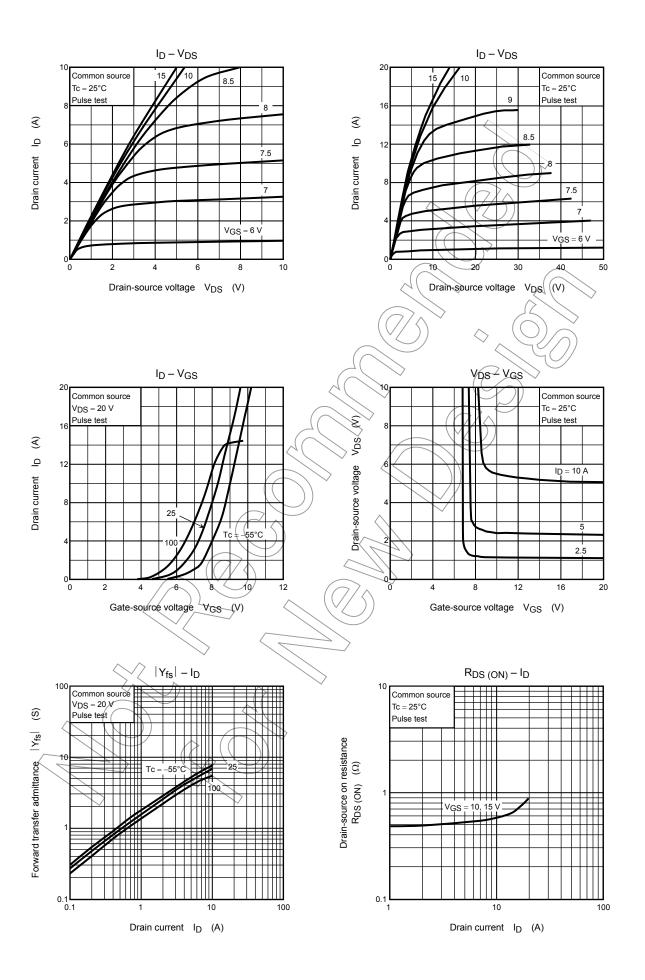
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Gate -source bre	akdown voltage	V (BR) GSS	$I_G=\pm 10~\mu A,~V_{DS}=0~V$	±30	_	_	V
Drain cut-off curre	ent	I _{DSS}	V _{DS} = 450 V, V _{GS} = 0 V		_	100	μА
Drain-source brea	akdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	450 550) -	_	V
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	3.0	_	5.0	V
Drain-source ON resistance		R _{DS} (ON)	V _{GS} = 10 V, I _D = 5 A	()	0.48	0.65	Ω
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 5 A	1.5	4.3	_	S
Input capacitance		C _{iss}		_	920	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	12	_	pF
Output capacitance		Coss			(140	\rightarrow	
Switching time	Rise time	t _r	V _{GS} ID = 5 Å		25	> —	
	Turn-on time	t _{on}	0 V RI - 40 O		35		ns
	Fall time	t _f	Duty ≤ 1%, t _w = 10 μs V _{DD} ~ 200 V		10		113
	Turn-off time	t _{off}	υυν 176, τω 10 μς	_	60	_	
Total gate charge	gate charge Qg			_	23	_	
Gate-source charge		Qgs	$V_{DD} \simeq 360 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$	_	9	_	nC
Gate-drain charge		$\left(\overrightarrow{Q}_{gd} \right)$		_	14	_	

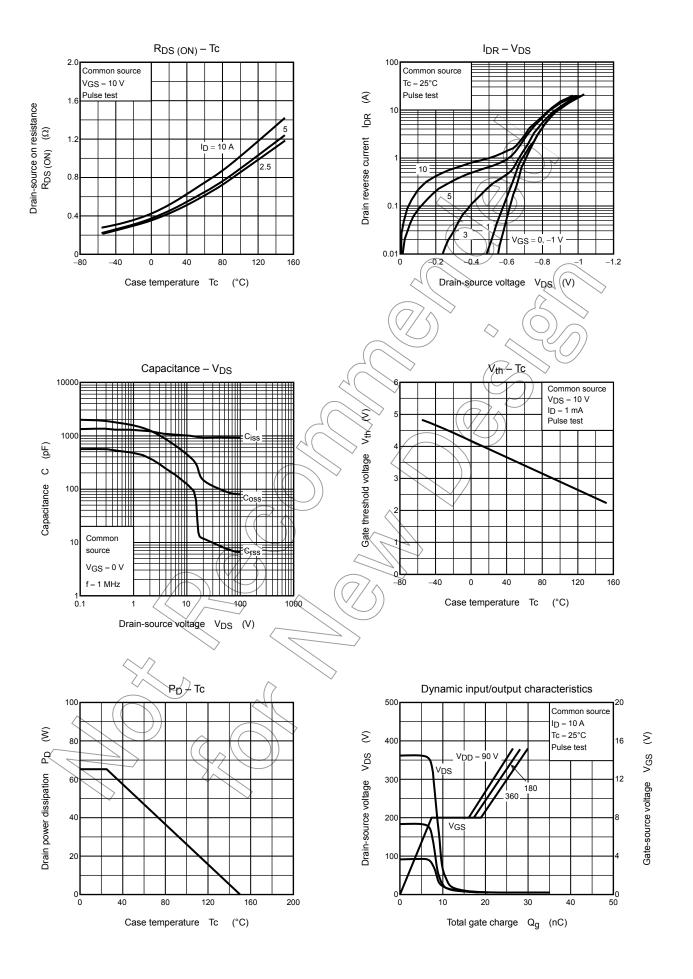
Source-Drain Ratings and Characteristics (Ta = 25°C)

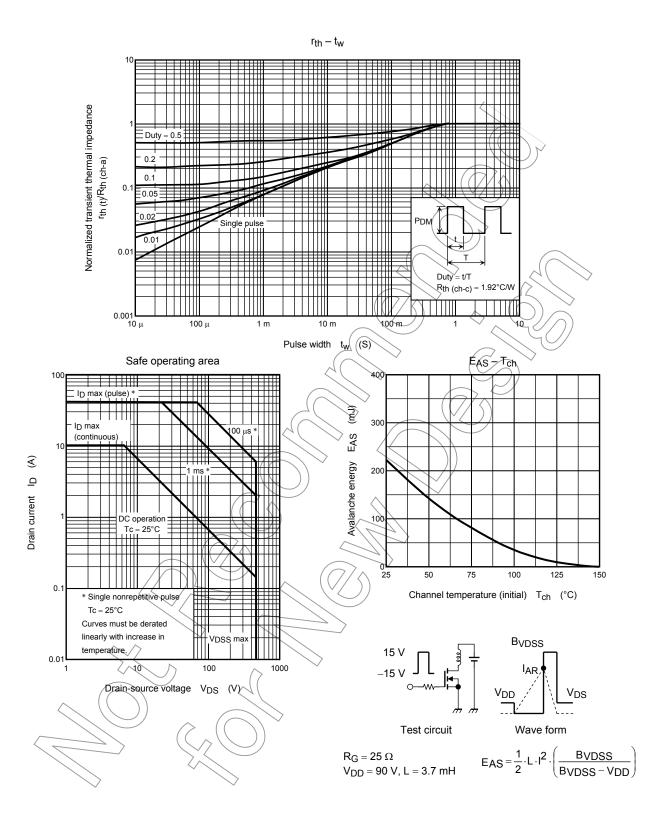
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	/br		_	_	10	Α
Pulse drain reverse current (Note 1)	IDRP		_	_	40	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 10 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	(t _{rr}	I _{DR} = 10 A, V _{GS} = 0 V,	_	280	_	ns
Reverse recovery charge	Qrr	dI _{DR} /dt = 100 A/μs	_	2.7	_	μС



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